TOSHIBA Photocoupler Photo Relay

TLP227GA, TLP227GA-2

Modem

Telecommunications

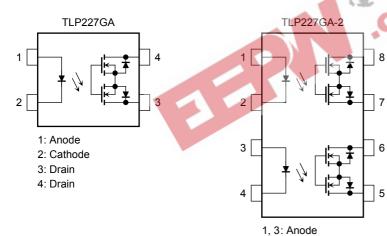
PBXs

The Toshiba TLP227GA series consist of a gallium arsenide infrared-emitting diode optically coupled to a photo-MOSFET in a 4-pin DIP or a 8-pin DIP package, and has a peak off-State voltage of 400 V.

• Normally off function

 $\begin{array}{lll} \bullet & TLP227GA & : DIP4 \ (1 \ form \ A) \\ & TLP227GA-2 & : DIP8 \ (2 \ form \ A) \\ \bullet & Peak \ off\mbox{-state voltage} & : 400 \ V \ (min) \\ \bullet & Trigger \ LED \ current & : 3 \ mA \ (max) \\ \bullet & On\mbox{-state current} & : 120 \ mA \ (max) \\ \bullet & On\mbox{-state resistance} & : 35\Omega \ (max) \\ \bullet & Isolation \ voltage & : 2500 \ Vrms \ (min) \\ \end{array}$

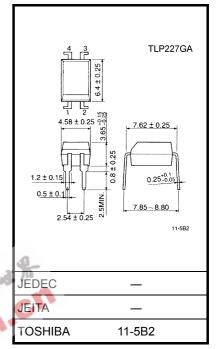
Pin Configuration (top view)



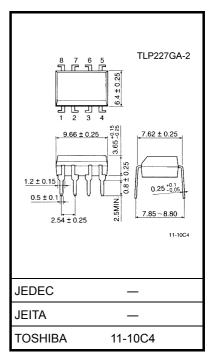
2, 4: Cathode5 : Drain D16 : Drain D27 : Drain D3

: Drain D4

Unit: mm



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Absolute Maximum Rating (Ta = 25°C)

	C	Characteristic		Symbol	Rating	Unit
	Forward curr	ent		l _F	50	mA
	Forward curr	ent derating (Ta ≧ 25°C)	ΔI _F /°C	-0.5	mA/°C
Led	Peak forward (100 μs pulse			I _{FP}	1	Α
	Reverse volt	age		V _R	5	V
	Junction tem	perature		Tj	125	°C
	Off-state out	put terminal vo	Itage	V _{OFF}	400	V
		TLP227GA				
	On-state current	TLP227GA-2	One channel	I _{ON}	120	Ма
ctor		TLP227GA-2	Both channel			
Detector	On-state current rating (Ta ≥ 25°C)	TLP227GA				
		TLP227GA-2	One channel	Δl _{ON} /°C	-1.2	mA/°C
		TLF227GA-2	Both channel			
	Junction tem	perature		Tj	125	°C
Storage temperature range				T _{stg}	-55~125	°C
Ор	erating tempe	rature range		T _{opr}	-40~85	°C
Lea	ad soldering te	emperature (10	s)	T _{sol}	260	°C
Iso	lation voltage	(AC, 1 min., R.	H. ≦ 60%) (Note 1)	BVs	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: LED pins are shorted together. Detector pins are also shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_		320	V
Forward current	lF	5	7.5	25	mA
On-state current	I _{ON}	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V_{F}	I _F = 10 mA	1.0	1.15	1.3	V
Led	Reverse current	I _R	V _R = 5 V	_	_	10	μА
	Capacitance	C _T	V = 0, f = 1 MHz		30		pF
Detector	Off-state current	l _{OFF}	V _{OFF} = 400 V		_	1	μА
Dete	Capacitance	C _{OFF}	V = 0, f = 1 MHz	_	_	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	I _{ON} = 120 mA	_	1	3	mA
On-state resistance	R _{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$		18	35	Ω

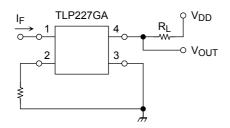
Isolation Characteristics (Ta = 25°C)

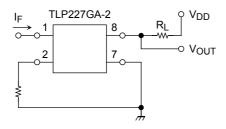
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V _S = 0 V, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≦ 60%	5 × 10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 min	2500	_	_	Vrmo
Isolation voltage	BV_S	AC, 1 s (in oil)	_	5000	_	Vrms
		DC, 1 min (in oil)	_	5000	_	Vdc

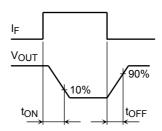
Switching Characteristics (Ta = 25°C)

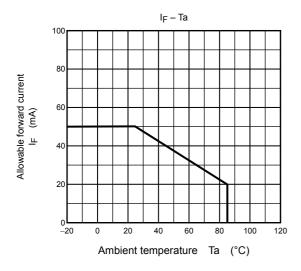
Characteristic	7	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time		ton	$R_L = 200 \Omega$	_	_	1	ms
Turn-off time		toff	$V_{DD} = 20 \text{ V, I}_F = 5 \text{ mA}$ (Note 2)	_	_	1	1113

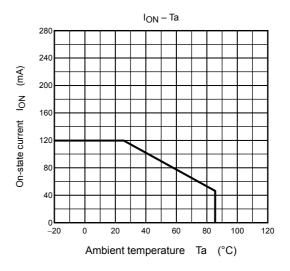
Note 2: Switching time test circuit

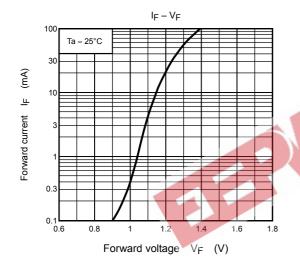


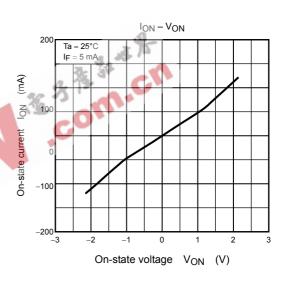


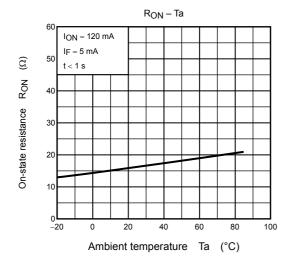


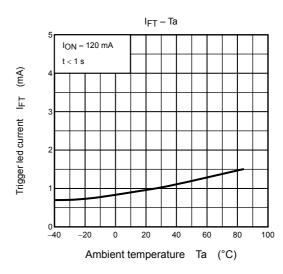


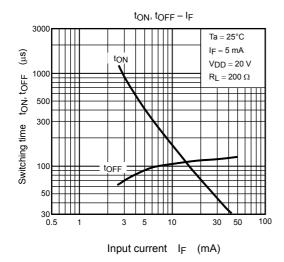


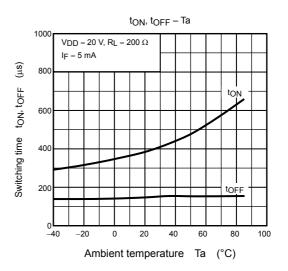


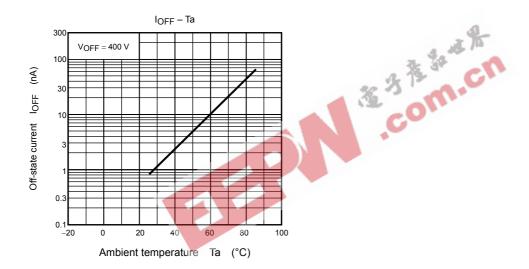












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